## UNITED STATES PATENT AND TRADEMARK OFFICE **CERTIFICATE OF CORRECTION**

PATENT NO. : 6,832,523 B2

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INVENTOR(S) : Hubert Benzel et al.

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

## Column 1,

Lines 35-36, change "using - and p-doped semiconductors" to -- using n- and p-doped semiconductors --.

Lines 41-42, change "by way of - and p-doped semiconductors areas" to -- by way of nand p-doped semiconductors areas --.

## Column 8,

Lines 1-2, change "at least one Pelter element" to -- at least one Peltier element --.

Signed and Sealed this

Sixteenth Day of August, 2005

JON W. DUDAS Director of the United States Patent and Trademark Office